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## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832
Email \& Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, \#122 Zhenhua RD., Futian, Shenzhen, China

## 4-/8-Channel Wideband Video Multiplexers

## FEATURES

- Wide Bandwidth: 500 MHz
- Very Low Crosstalk: -97 dB @ 5 MHz
- On-Board TTL-Compatible Latches with Readback
- Optional Negative Supply
- Low ros(on): $45 \Omega$
- Single-Ended or Differential Operation
- Latch-up Proof


## BENEFITS

- Improved System Bandwidth
- Improved Channel Off-Isolation
- Simplified Logic Interfacing
- High-Speed Readback
- Allows Bipolar Signal Swings
- Reduced Insertion Loss
- Allows Differential Signal Switching


## APPLICATIONS

- Wideband Signal Routing and Multiplexing
- Video Switchers
- ATE Systems
- Infrared Imaging
- Ultrasound Imaging


## DESCRIPTION

The DG534A is a digitally selectable 4-channel or dual 2-channel multiplexer. The DG538A is an 8-channel or dual 4-channel multiplexer. On-chip TTL-compatible address decoding logic and latches with data readback are included to simplify the interface to a microprocessor data bus. The low on-resistance and low capacitance of the these devices make them ideal for wideband data multiplexing and video and audio signal routing in channel selectors and crosspoint arrays. An optional negative supply pin allows the handling of bipolar signals without dc biasing.

The DG534A/DG538A are built on a D/CMOS process that combines n-channel DMOS switching FETs with low-power CMOS control logic, drivers and latches. The low-capacitance DMOS FETs are connected in a "T" configuration to achieve extremely high levels of off isolation. Crosstalk is reduced to -97 dB at 5 MHz by including a ground line between adjacent signal paths. An epitaxial layer prevents latch-up.

For more information refer to Vishay Siliconix applications note AN502.

## FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



Vishay Siliconix

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



| TRUTH TABLE - DG534A |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| I/O | $\mathrm{A}_{1}$ | $\mathrm{A}_{0}$ | EN | WR | RS | 4/2 ${ }^{\text {a }}$ | On Switch |  |
| X | X | X | X | 5 | 1 | 1 | Maintains previous state |  |
| X | X | X | X | X | 0 | X | None (latches cleared) |  |
| X | X | X | 0 | 0 | 1 | X | None |  |
| 0 | 0 | 0 | 1 | 0 | 1 | 0 | $\mathrm{S}_{\text {A1 }}$ |  |
| 0 | 0 | 1 | 1 | 0 | 1 | 0 | $\mathrm{S}_{\mathrm{A} 2} \quad \mathrm{D}_{\mathrm{A}}$ and $\mathrm{D}_{\mathrm{B}}$ may be |  |
| 0 | 1 | 0 | 1 | 0 | 1 | 0 | $\mathrm{S}_{\mathrm{B} 1}$ connected externally | Latches Transparent |
| 0 | 1 | 1 | 1 | 0 | 1 | 0 | $\mathrm{S}_{\mathrm{B} 2}$ |  |
| 0 | X | 0 | 1 | 0 | 1 | 1 | $\mathrm{S}_{\mathrm{A} 1}$ and $\mathrm{S}_{\mathrm{B} 1}$ |  |
| 0 | X | 1 | 1 | 0 | 1 | 1 | $\mathrm{S}_{\mathrm{A} 2}$ and $\mathrm{S}_{\mathrm{B} 2}$ |  |
| 1 | Note b |  |  | 1 | 1 | Note c |  |  |

Logic " 0 " $=\mathrm{V}_{\mathrm{AL}} \leq 0.8 \mathrm{~V}$
Logic " 1 " $=\mathrm{V}_{\mathrm{AH}} \geq 2.4 \mathrm{~V}$
X = Don't Care

DG534A/538A
Vishay Siliconix

| TRUTH TABLE - DG538A |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| İ/O | $\mathrm{A}_{2}$ | $\mathrm{A}_{1}$ | $\mathrm{A}_{0}$ | EN | WR | RS | 8/4a | On Switch |  |
| x | x | X | x | x | $\checkmark$ | 1 | 1 | Maintains previous state |  |
| X | X | X | X | X | $\times$ | 0 | X | None (latches cleared) |  |
| X | X | X | X | 0 | 0 | 1 | X | None | Latches Transparent |
| 0 | 0 | 0 | 0 | 1 | 0 | 1 | 0 | $\mathrm{D}_{\mathrm{A}}$ and $\mathrm{D}_{\mathrm{B}}$ should be connected externally |  |
| 0 | 0 | 0 | 1 | 1 | 0 | 1 | 0 |  |  |
| 0 | 0 | 1 | 0 | 1 | 0 | 1 | 0 |  |  |
| 0 | 0 | 1 | 1 | 1 | 0 | 1 | 0 |  |  |
| 0 | 1 | 0 | 0 | 1 | 0 | 1 | 0 |  |  |
| 0 | 1 | 0 | 1 | 1 | 0 | 1 | 0 |  |  |
| 0 | 1 | 1 | 0 | 1 | 0 | 1 | 0 |  |  |
| 0 | 1 | 1 | 1 | 1 | 0 | 1 | 0 |  |  |
| 0 | X | 0 | 0 | 1 | 0 | 1 | 1 | $\mathrm{S}_{\mathrm{A} 1}$ and $\mathrm{S}_{\mathrm{B} 1}$ |  |
| 0 | X | 0 | 1 | 1 | 0 | 1 | 1 | $\mathrm{S}_{\mathrm{A} 2}$ and $\mathrm{S}_{\mathrm{B} 2}$ |  |
| 0 | X | 1 | 0 | 1 | 0 | 1 | 1 | $\mathrm{S}_{\mathrm{A} 3}$ and $\mathrm{S}_{\mathrm{B} 3}$ |  |
| 0 | X | 1 | 1 | 1 | 0 | 1 | 1 | $\mathrm{S}_{\mathrm{A} 4}$ and $\mathrm{S}_{\mathrm{B} 4}$ |  |
| 1 | Note b |  |  |  | 1 | 1 | Note c |  |  |
| $\begin{gathered} \text { Logic " } 0 \text { " }=V_{\text {AL }} \leq 0.8 \mathrm{~V} \\ \text { Logic " } 1 \text { " }=V_{A H} \geq 2 \mathrm{~V} \\ X=\text { Don't Care } \end{gathered}$ |  |  |  |  |  |  |  |  |  |

Notes:
a. Connect $D_{A}$ and $D_{B}$ together externally for single-ended operation.
b. With I/O high, $\mathrm{A}_{\mathrm{n}}$ and EN pins become outputs and reflect latch contents. See timing diagrams for more detail.
c. $\overline{8} / 4$ can be either " 1 " or " 0 " but should not change during these operations.

| ORDERING INFORMATION |  |  |  |
| :--- | :---: | :--- | :---: |
| Temperature Range | Package | Part Number |  |
| DG534A |  |  |  |
| -40 to $85^{\circ} \mathrm{C}$ | 20-Pin Plastic DIP | DG534ADJ |  |
|  | 20-Pin PLCC | DG534ADN |  |
|  | 20-Pin Sidebraze | DG534AAP/883, 5962-906021MRC |  |
|  |  |  |  |
| DG538A |  |  |  |
| -40 to $85^{\circ} \mathrm{C}$ | 28-Pin Plastic DIP | DG538ADJ |  |
|  | 28-Pin PLCC | DG538ADN |  |
| -55 to $125^{\circ} \mathrm{C}$ | 28-Pin Sidebraze | DG538AAP/883, 5962-8976001MXA |  |

## ABSOLUTE MAXIMUM RATINGS

| V+ to GND | -0.3 V to +21 V | Storage Temperature | (A Suffix) | -65 to $150^{\circ} \mathrm{C}$ |
| :---: | :---: | :---: | :---: | :---: |
| $V+$ to V- | . -0.3 V to +21 V |  | (D Suffix) | -65 to $125^{\circ} \mathrm{C}$ |
| V - to GND | -10 V to +0.3 V | Power Dissipation (Package) ${ }^{\text {a }}$ |  |  |
| V | . 0 V to $(\mathrm{V}+)+0.3 \mathrm{~V}$ | Plastic DIPb |  | 625 mW |
| Digital Inputs | $\ldots . .(\mathrm{V}-)-0.3 \mathrm{~V} \text { to }\left(\mathrm{V}_{\mathrm{L}}\right)+0.3 \mathrm{~V}$ <br> or 20 mA , whichever occurs first | PLCC ${ }^{\text {. . . }}$ Sidebraze ${ }^{\text {d }}$ |  | $\begin{aligned} & . .450 \mathrm{~mW} \\ & .1200 \mathrm{~mW} \end{aligned}$ |
| $V_{S}, V_{D}$ | $\ldots . .(\mathrm{V}-)-0.3 \mathrm{~V} \text { to }(\mathrm{V}-)+14 \mathrm{~V}$ <br> or 20 mA , whichever occurs first | Notes: <br> a. All leads soldered or welded to $P$ <br> b. Derate $8.3 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $75^{\circ} \mathrm{C}$. <br> c. Derate $6 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $75^{\circ} \mathrm{C}$. <br> d. Derate $16 \mathrm{~mW} /{ }^{\circ} \mathrm{C}$ above $75^{\circ} \mathrm{C}$. |  |  |
| Current (any terminal) Continuous | ... 20 mA |  |  |  |
| Current(S or D) Pulsed I ms 10\% Duty | ................... 40 mA |  |  |  |


| SPECIFICATIONS ${ }^{\text {a }}$ |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Parameter | Symbol | Test Conditions Unless Otherwise Specified$\begin{gathered} V_{+}=15 \mathrm{~V}, \mathrm{~V}-=-3 \mathrm{~V}, \mathrm{~V}_{\mathrm{L}}=5 \mathrm{~V} \\ \mathrm{WR}=0.8 \mathrm{~V}, \mathrm{RS}, \mathrm{EN}=2 \mathrm{~V} \end{gathered}$ | Temp ${ }^{\text {b }}$ | Typ ${ }^{\text {c }}$ | A Suffix <br> -55 to $125^{\circ} \mathrm{C}$ |  | D Suffix <br> -40 to $85^{\circ} \mathrm{C}$ |  | Unit |
|  |  |  |  |  | Mind ${ }^{\text {d }}$ | Max ${ }^{\text {d }}$ | Min ${ }^{\text {d }}$ | Max ${ }^{\text {d }}$ |  |
| Analog Switch |  |  |  |  |  |  |  |  |  |
| Analog Signal Range ${ }^{9}$ | $\mathrm{V}_{\text {ANALOG }}$ | $\mathrm{V}-=-5 \mathrm{~V}$ | Full |  | -5 | 8 | -5 | 8 | V |
| Drain-Source On-Resistance | $r_{\text {DS }}$ (on) | $\begin{gathered} I_{\mathrm{S}}=-10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{S}}=0 \mathrm{~V} \\ \mathrm{~V}_{\mathrm{AIL}}=0.8 \mathrm{~V}, \mathrm{~V}_{\text {AIH }}=2 \mathrm{~V} \\ \text { Sequence Each Switch On } \end{gathered}$ | Room Full | 45 |  | $\begin{gathered} 90 \\ 120 \end{gathered}$ |  | $\begin{gathered} 90 \\ 120 \end{gathered}$ | $\Omega$ |
| Resistance Match Between Channels | $\Delta r_{\text {DS(on) }}$ |  | Room |  |  | 9 |  | 9 |  |
| Source Off <br> Leakage Current | $\mathrm{I}_{\text {(off) }}$ | $\mathrm{V}_{\mathrm{S}}=8 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=0 \mathrm{~V}, \mathrm{EN}=0.8 \mathrm{~V}$ | Room Full | 0.05 | $\begin{gathered} \hline-5 \\ -50 \end{gathered}$ | $\begin{gathered} \hline 5 \\ 50 \end{gathered}$ | $\begin{gathered} \hline-5 \\ -50 \end{gathered}$ | $\begin{gathered} \hline 5 \\ 50 \end{gathered}$ |  |
| Drain Off Leakage Current | $I_{\text {( } \text { (ff) }}$ | $\mathrm{V}_{S}=0 \mathrm{~V}, \mathrm{~V}_{\mathrm{D}}=8 \mathrm{~V}, \mathrm{EN}=0.8 \mathrm{~V}$ | Room Full | 0.1 | $\begin{gathered} \hline-20 \\ -500 \end{gathered}$ | $\begin{gathered} 20 \\ 500 \end{gathered}$ | $\begin{gathered} -20 \\ -100 \end{gathered}$ | $\begin{gathered} 20 \\ 100 \end{gathered}$ | nA |
| Drain On Leakage Current | $I_{\text {(on) }}$ | $\mathrm{V}_{S}=\mathrm{V}_{\mathrm{D}}=8 \mathrm{~V}$ | $\begin{gathered} \hline \text { Room } \\ \text { Full } \end{gathered}$ | 0.1 | $\begin{gathered} -20 \\ -1000 \end{gathered}$ | $\begin{gathered} \hline 20 \\ 1000 \end{gathered}$ | $\begin{gathered} -20 \\ -200 \end{gathered}$ | $\begin{gathered} 20 \\ 200 \end{gathered}$ |  |
| Digital Control |  |  |  |  |  |  |  |  |  |
| Input Voltage High | $\mathrm{V}_{\text {AIH }}$ |  | Full |  | 2 |  | 2 |  | V |
| Input Voltage Low | $\mathrm{V}_{\text {AIL }}$ |  | Full |  |  | 0.8 |  | 0.8 |  |
| Address Input Current | $\mathrm{I}_{\mathrm{Al}}$ | $\mathrm{V}_{\mathrm{Al}}=0 \mathrm{~V}$, or 2 V or 5 V | Room Full | -0.1 | $\begin{gathered} \hline-1 \\ -10 \end{gathered}$ | $\begin{gathered} 1 \\ 10 \end{gathered}$ | $\begin{gathered} \hline-1 \\ -10 \end{gathered}$ | $\begin{gathered} 1 \\ 10 \end{gathered}$ | $\mu \mathrm{A}$ |
| Address Output Current | $\mathrm{I}_{\mathrm{AO}}$ | $\mathrm{V}_{\mathrm{AO}}=2.7 \mathrm{~V}$ | Room | -21 |  | -2.5 |  | -2.5 | mA |
|  |  | $\mathrm{V}_{\mathrm{AO}}=0.4 \mathrm{~V}$ | Room | 3.5 | 2.5 |  | 2.5 |  |  |
| Dynamic Characteristics |  |  |  |  |  |  |  |  |  |
| On State Input Capacitance ${ }^{\text {g }}$ | $\mathrm{C}_{\text {S(on) }}$ | See Figure 11 | Room | 28 |  | 40 |  | 40 | pF |
|  |  |  | Room | 31 |  | 45 |  | 45 |  |
| Off State Input Capacitance ${ }^{g}$ | $\mathrm{C}_{\text {S(off) }}$ | See Figure 12 | Room | 3 |  | 5 |  | 4 |  |
|  |  |  | Room | 4 |  |  |  | 5 |  |
| Off State Output Capacitance ${ }^{9}$ | $C_{D(\text { off })}$ |  | Room | 6 |  | 10 |  | 8 |  |
|  |  |  | Room | 8 |  |  |  | 10 |  |
| Transition Time | $t_{\text {trans }}$ | See Figure 4 | Room Full | 160 |  | $\begin{aligned} & 300 \\ & 500 \end{aligned}$ |  | $\begin{aligned} & 300 \\ & 500 \end{aligned}$ | ns |
| Break-Before-Make Interval | topen |  | Room Full | 80 | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ |  | $\begin{aligned} & 50 \\ & 25 \end{aligned}$ |  |  |
| EN, WR Turn On Time | $\mathrm{t}_{\mathrm{ON}}$ | See Figure 2 and 3 | Room Full | 150 |  | $\begin{aligned} & 300 \\ & 500 \end{aligned}$ |  | $\begin{aligned} & 300 \\ & 500 \end{aligned}$ |  |
| EN, Turn Off Time | tofF | See Figure 2 | Room Full | 105 |  | $\begin{aligned} & 175 \\ & 300 \end{aligned}$ |  | $\begin{aligned} & 175 \\ & 300 \end{aligned}$ |  |
| Charge Injection | Qi | See Figure 5 | Room | -70 |  |  |  |  | pC |



## Notes:

a. Refer to PROCESS OPTION FLOWCHART.
b. Room $=25^{\circ} \mathrm{C}$, Full = as determined by the operating temperature suffix.
c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing
d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
e. Defined by system bus requirements.
f. Each individual pin shown as GND must be grounded.
g. Guaranteed by design, not subject to production test.

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CONTROL CIRCUITRY

*Typical all Readback ( $\mathrm{A}_{\mathrm{x}}, \mathrm{EN}$ ) pins






Adjacent Input Crosstalk vs. Frequency


TYPICAL CHARACTERISTICS ( $25^{\circ} \mathrm{C}$ UNLESS NOTED)





f - Frequency (MHz)


TYPICAL CHARACTERISTICS ( $\mathbf{2 5}^{\circ}$ C UNLESS NOTED)



## OUTPUT TIMING REQUIREMENTS



Delay Time Required after Reset before Write


FIGURE 1.

## TEST CIRCUITS



FIGURE 2. EN, CS, CS, Turn On/Off Time


FIGURE 3. WR, Turn On Time

TEST CIRCUITS


FIGURE 4. Transition Time and Break-Before-Make Interval

$\Delta V_{\text {OUT }}$ is the measured voltage error due to charge injection. The charge injection in Coulombs is $\mathrm{Q}=\mathrm{C}_{\mathrm{L}} \times \Delta \mathrm{V}_{\mathrm{OUT}}$

FIGURE 5. Charge Injection

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## TEST CIRCUITS



FIGURE 6. Bandwidth


FIGURE 7. All Hostile Crosstalk

$$
X_{\text {TALK(Al) }}=20 \log _{10} \frac{v_{\mathrm{Sn}-1}}{v_{\mathrm{Sn}}} \text { or } 20 \log _{10} \frac{v_{\mathrm{Sn}+1}}{v_{\mathrm{Sn}}}
$$

FIGURE 9. Adjacent Input Crosstalk



FIGURE 10. Differential Crosstalk

## TEST CIRCUITS




Notes:
a. Both $V+$ and $V$ - must have decoupling capacitors mounted as close as possible to the device pins. Typical decoupling capacitors would be $10-\mu \mathrm{F}$ tantalum bead in parallel with $100-\mathrm{nF}$ ceramic disc.
. Production tested with $\mathrm{V}+=15 \mathrm{~V}$ and $\mathrm{V}-=-3 \mathrm{~V}$.
a. For $\mathrm{V}_{\mathrm{L}}=5 \mathrm{~V} \pm 10 \%, 0.8$ - or $2-\mathrm{V}$ TTL compatibility is maintained over the entire operating voltage range.

## PIN DESCRIPTION

| Symbol | Pin Number |  | Description |
| :---: | :---: | :---: | :---: |
|  | DG534ADJ | DG538A |  |
| $\mathrm{D}_{\mathrm{A}}$ | 2 | 2 | Analog Output/Input |
| $\mathrm{v}_{+}$ | 3 | 3 | Positive Supply Voltage |
| $\mathrm{s}_{\mathrm{A} 1}$ | 4 | 4 | Analog InputOutput |
| $\mathrm{S}_{\mathrm{A} 2}$ | 6 | 6 | Analog InputOutput |
| $\mathrm{S}_{\text {A }}$ | - | 8 | Analog InputOutput |
| $\mathrm{S}_{\mathrm{A} 4}$ | - | 10 | Analog InputOutput |
| 4/2 | 7 | - | $4 \times 1$ or $2 \times 2$ Select |
| 8/4 | - | 11 | $8 \times 1$ or $4 \times 2$ Select |
| RS | 8 | 12 | Reset |
| WR | 9 | 13 | Write command that latches A, EN |
| $\mathrm{A}_{0}, A_{1}, A_{2}$ | 11, 10, - | 16, 15, 14 | Binary address inputs that determine which channel(s) is/are connected to the output(s) |
| En | 12 | 17 | Enable. Input/Output, if $\mathrm{EN}=0$, all channels are open |
| I/ | 13 | 18 | Input/Output control. Used to write to or read from the address latches |
| $\mathrm{v}_{\mathrm{L}}$ | 14 | 19 | Logic Supply Voltage, usually +5 V |
| $\mathrm{S}_{\text {B4 }}$ | - | 20 | Analog Input/Output |
| $\mathrm{S}_{\text {B3 }}$ | - | 22 | Analog Input/Output |
| $\mathrm{S}_{\mathrm{B} 2}$ | 15 | 24 | Analog InputOutput |
| $\mathrm{S}_{\mathrm{B} 1}$ | 17 | 26 | Analog InputOutput |
| V - | 18 | 27 | Negative Supply Voltage |
| $\mathrm{D}_{\mathrm{B}}$ | 19 | 28 | Analog Output/lnput |
| GND | 1, 5, 16 | 1, 5, 7, 9, 21, 23, 25 | Analog and Digital Grounds. All grounds should be connected externally to optimize dynamic performance |

## APPLICATIONS

## Device Description

The DG534A/538A D/CMOS wideband multiplexers offer single-ended or differential functions. A $\overline{8} / 4$ or $\overline{4} / 2$ logic input pin selects the single-ended or differential mode.

To meet the high dynamic performance demands of video, high definition TV, digital data routing (in excess of 100 Mbps ), etc., the DG534A/538A are fabricated with DMOS transistors configured in 'T' arrangements with second level 'L' configurations (see Functional Block Diagram).

Use of DMOS technology yields devices with very low capacitance and low $\mathrm{r}_{\mathrm{DS}}(\mathrm{on})$. This directly relates to improved high frequency signal handling and higher switching speeds, while maintaining low insertion loss figures. The 'T' and 'L' switch configurations further improve dynamic performance by greatly reducing crosstalk and output node capacitances.

The DG534A/DG538A are improved pin-compatible replacements for the non-A versions. Improvements include: higher current readback drivers, readback of the EN bit, latchup protection

## Frequency Response

A single multiplexer on-channel exhibits both resistance [ $\mathrm{r}_{\mathrm{DS}(o n)}$ ] and capacitance $\left[\mathrm{C}_{\mathrm{S}(\mathrm{on})}\right.$ ]. This RC combination causes a frequency dependent attenuation of the analog signal. The $-3-\mathrm{dB}$ bandwidth of the DG534A/538A is typically 500 MHz (into $50 \Omega$ ). This figure of 500 MHz illustrates that the switch-channel cannot be represented by a simple RC combination. The on capacitance of the channel is distributed along the on-resistance, and hence becomes a more complex multi-stage network of R's and C's making up the total ras(on) and $\mathrm{C}_{\mathrm{S}(\mathrm{on})}$.

## APPLICATIONS (CONT’D)

## Power Supplies and Decoupling

A useful feature of the DG534A/538A is its power supply flexibility. It can be operated from unipolar supplies (Vconnected to 0 V ) if required. Allowable operating voltage ranges are shown in Figure 13.

Note that the analog signal must not go below V - by more than 0.3 V (see absolute maximum ratings). However, the addition of a V - pin has a number of advantages:
a. It allows flexibility in analog signal handling, i.e. with $\mathrm{V}-=$ -5 V and $\mathrm{V}_{+}=15 \mathrm{~V}$, up to $\pm 5 \mathrm{~V}$ ac signals can be accepted.
b. The value of on capacitance $\left(\mathrm{C}_{\mathrm{S}(\mathrm{on})}\right)$ may be reduced by increasing the reverse bias across the internal FET body to source junction. $\mathrm{V}_{+}$has no effect on $\mathrm{C}_{\mathrm{S}(o n)}$.
It is useful to note that tests indicate that optimum video differential phase and gain occur when V - is -3 V .
c. V- eliminates the need to bias an ac analog signal using potential dividers and large decoupling capacitors.

It is established rf design practice to incorporate sufficient bypass capacitors in the circuit to decouple the power supplies to all active devices in the circuit. The dynamic performance of the DG534/538 is adversely affected by poor decoupling of power supply pins. Also, since the substrate of the device is connected to the negative supply, proper decoupling of this pin is essential.

## Rules:

a. Decoupling capacitors should be incorporated on all power supply pins ( $\mathrm{V}_{+}, \mathrm{V}_{-}, \mathrm{V}_{\mathrm{L}}$ ).
b. They should be mounted as close as possible to the device pins.
c. Capacitors should have good frequency characteristics tantalum bead and/or ceramic disc types are suitable. Recommended decoupling capacitors are 1- to $10-\mu \mathrm{F}$ tantalum bead, in parallel with $100-\mathrm{nF}$ ceramic or polyester.
d. Additional high frequency protection may be provided by $51-\Omega$ carbon film resistors connected in series with the power supply pins (see Figure 14).

## Board Layout

PCB layout rules for good high frequency performance must also be observed to achieve the performance boasted by the DG534A/538A. Some tips for minimizing stray effects are:
a. Use extensive ground planes on double sided PCB separating adjacent signal paths. Multilayer PCB is even better.
b. Keep signal paths as short as practically possible with all channel paths of near equal length.
c. Use strip-line layout techniques.

Improvements in performance can be obtained by using PLCC parts instead of DIPs. The stray effects of the quad PLCC package are lower than those of the dual-in-line packages. Sockets for the PLCC packages usually increase crosstalk.


FIGURE 14. DG534A Power Supply Decoupling

## Interfacing

Logic interfacing is easily accomplished. Comprehensive addressing and control functions are incorporated in the design.

The $V_{L}$ pin permits interface to various logic types. The device is primarily designed to be TTL or CMOS logic compatible with +5 V applied to $\mathrm{V}_{\mathrm{L}}$. The actual logic threshold can be raised simply by increasing $\mathrm{V}_{\mathrm{L}}$.

## APPLICATIONS (CONT'D)

A typical switching threshold versus $\mathrm{V}_{\mathrm{L}}$ is shown in Figure 15.

These devices feature an address readback (Tally) facility, whereby the last address written to the device may be output to the system. This allows improved status monitoring and hand shaking without additional external components.

This function is controlled by the $\overline{/} / \mathrm{O}$ pin, which directly addresses the tri-state buffers connected to the EN and address pins. EN and address pins can be assigned to accept data (when $\overline{\mathrm{I}} / \mathrm{O}=0 ; \overline{\mathrm{WR}}=0 ; \overline{\mathrm{RS}}=1$ ), or output data (when $\overline{\mathrm{I}} / \mathrm{O}=$ $1 ; \overline{W R}=1 ; \overline{R S}=1$ ), or to reflect a high impedance and latched state ( $w$ when $\mathrm{T} / \mathrm{O}=0 ; \mathrm{WR}=1 ; \mathrm{RS}=1$ ).

When I/O is high, the address output can sink or source current. Note that $V_{L}$ is the logic high output condition. This point must be respected if $\mathrm{V}_{\mathrm{L}}$ is varied for input logic threshold shifting.

Further control pins facilitate easy microprocessor interface. On chip address, data latches are activated by WR, which serves as a strobe type function eliminating the need for peripheral latch or memory I/O port devices. Also, for ease of interface, a direct reset function ( $\overline{\mathrm{RS}}$ ) allows all latches to be cleared and switches opened. Reset should be used during power up, etc., to avoid spurious switch action. See Figure 16.

Channel address data can only be entered during WR low, when the address latches are transparent and I/O is low. Similarly, address readback is only operational when WR and $\mathrm{I} / \mathrm{O}$ are high.

The Siliconix CLC410 Video amplifier is recommended as an output buffer to reduce insertion loss and to drive coaxial cables. For low power video routing applications or for unity gain input buffers CLC111/CLC114 are recommended.


FIGURE 15. Switching Threshold Voltage vs. $\mathrm{V}_{\mathrm{L}}$


FIGURE 16. DG534A in a Video Matrix

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